

Nch 200V 7.5A Power MOSFET

| V _{DSS} | 200V |
|----------------------------|-------|
| R _{DS(on)} (Max.) | 325mΩ |
| I _D | ±7.5A |
| P _D | 52W |

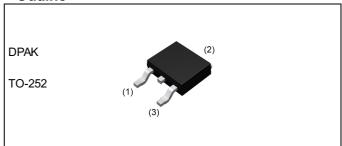
●Features

- 1) Low on-resistance
- 2) Fast switching speed
- 3) Drive circuits can be simple
- 4) Parallel use is easy
- 5) Pb-free plating; RoHS compliant

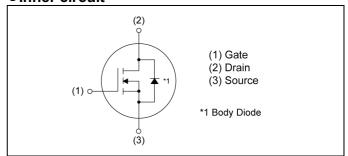
Application

Switching Power Supply

Outline



•Inner circuit



Packaging specifications

| Туре | Packing | Embossed Tape |
|------|-----------------|------------------|
| | Reel size (mm) | 330 |
| | Tape width (mm) | 16 |
| | Quantity (pcs) | 2500 |
| | Taping code | TL1 |
| | Marking | RD3T075CN |

● **Absolute maximum ratings** (T_a = 25°C ,unless otherwise specified)

| Parameter | | Symbol | Value | Unit |
|---|------------------------|--------------------|-------|------|
| Drain - Source voltage | | V_{DSS} | 200 | V |
| Ocation and decision and | T _c = 25°C | I _D *1 | ±7.5 | Α |
| Continuous drain current | T _c = 100°C | I _D *1 | ±4.1 | Α |
| Pulsed drain current | | I _{DP} *2 | ±30 | Α |
| Gate - Source voltage | | V_{GSS} | ±30 | V |
| Avalanche energy, single pulse | | E _{AS} *3 | 4.13 | mJ |
| Avalanche current, single pulse | | I _{AS} *3 | 3.75 | Α |
| Power dissipation (T _c = 25°C) | | P _D | 52 | W |
| Junction temperature | | T _j | 150 | °C |
| Operating junction and storage te | T _{stg} | -55 to +150 | °C | |

●Thermal resistance

| Doromotor | Symbol | Values | | | Lleit |
|--|-------------------|--------|------|------|-------|
| Parameter | Symbol | Min. | Тур. | Max. | Unit |
| Thermal resistance, junction - case | R _{thJC} | - | - | 2.36 | °C/W |
| Soldering temperature, wavesoldering for 10s | T _{sold} | - | - | 265 | °C |

● Electrical characteristics (T_a = 25°C)

| Downwater | Cymah al | Conditions | Values | | | Unit | |
|--|--|---|--------|------|------|-------|--|
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Uniil | |
| Drain - Source breakdown voltage | $V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$ | | 200 | - | - | V | |
| Zero gate voltage | 1 | V _{DS} = 200V, V _{GS} = 0V | | | | | |
| drain current | I _{DSS} | $T_j = 25^{\circ}C$ | - | - | 10 | μA | |
| Gate - Source leakage current | I _{GSS} | $V_{GS} = \pm 30V, V_{DS} = 0V$ | 1 | 1 | ±100 | nA | |
| Gate threshold voltage | V _{GS(th)} | V _{DS} = 10V, I _D = 1mA | 3.25 | 1 | 5.25 | V | |
| Static drain - source on - state resistance | R _{DS(on)} *4 | $V_{GS} = 10V, I_D = 3.75A$ | - | 250 | 325 | mΩ | |
| Forward Transfer Admittance | Y _{fs} *4 | V _{DS} = 10V, I _D = 3.75A | 1.5 | 3.0 | - | S | |

^{*1} Limited only by maximum temperature allowed.

^{*2} Pw \leq 10µs, Duty cycle \leq 1%

^{*3} L \simeq 500 μ H, V_{DD} = 50V, R_G = 25 Ω , starting T $_j$ = 25°C

^{*4} Pulsed

● Electrical characteristics (T_a = 25°C)

| Deremeter | Symbol | Conditions | Values | | | Unit |
|------------------------------|------------------------|---------------------------------------|--------|------|------|------|
| Parameter Symbol | | Conditions | Min. | Тур. | Max. | Unit |
| Input capacitance | C _{iss} | V _{GS} = 0V | - | 755 | - | |
| Output capacitance | C _{oss} | V _{DS} = 25V | - | 55 | - | pF |
| Reverse transfer capacitance | C _{rss} | f = 1MHz | - | 25 | - | |
| Turn - on delay time | $t_{d(on)}^{*4}$ | $V_{DD} \simeq 100V$, $V_{GS} = 10V$ | - | 20 | - | |
| Rise time | t _r *4 | I _D = 3.75A | - | 22 | - | no |
| Turn - off delay time | t _{d(off)} *4 | $R_L \simeq 26.67\Omega$ | - | 24 | - | ns |
| Fall time | t _f *4 | $R_G = 10\Omega$ | _ | 12 | - | |

● Gate charge characteristics (T_a = 25°C)

| Darameter | Cumphal | Conditions | Values | | | l leit |
|----------------------|------------------------|---|--------|------|------|--------|
| Parameter Symbol Co | | Conditions | Min. | Тур. | Max. | Unit |
| Total gate charge | Q_g^{*4} | V _{DD} ≈ 100V | - | 15 | - | |
| Gate - Source charge | Q _{gs} *4 | I _D = 7.5A | - | 6 | - | nC |
| Gate - Drain charge | Q _{gd} *4 | V _{GS} = 10V | - | 6 | - | |
| Gate plateau voltage | V _(plateau) | V _{DD} ≈ 100V, I _D = 7.5A | - | 7.4 | - | V |

● Body diode electrical characteristics (Source-Drain) (T_a = 25°C)

| Parameter | Symbol | Conditions | Values | | | Unit |
|----------------------------|--------------------|-----------------------------|--------|------|------|-------|
| Farameter | Symbol Conditions | | Min. | Тур. | Max. | Offic |
| Continuous forward current | I _S *1 | T- = 25°C | 1 | 1 | 7.5 | Α |
| Pulse forward current | I _{SP} *2 | T _C = 25°C | 1 | 1 | 30 | Α |
| Forward voltage | V _{SD} *4 | $V_{GS} = 0V, I_{S} = 7.5A$ | ı | ı | 1.5 | V |
| Reverse recovery time | t _{rr} *4 | I _S = 3.8A | - | 70 | - | ns |
| Reverse recovery charge | Q _{rr} *4 | di/dt = 100A/µs | - | 180 | ı | nC |

Fig.1 Power Dissipation Derating Curve

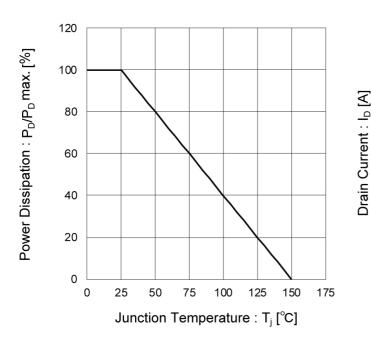


Fig.2 Maximum Safe Operating Area

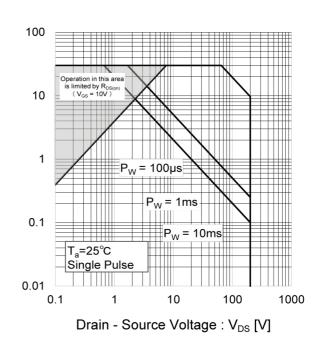
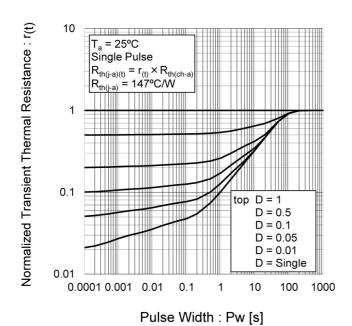


Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width



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Fig.4 Avalanche Current vs. Inductive Load

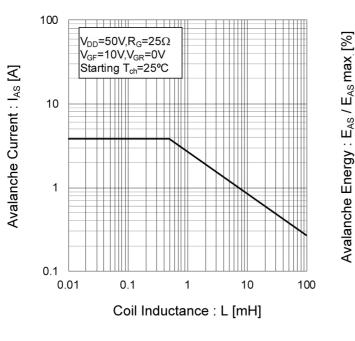


Fig.5 Avalanche Energy Derating Curve vs. Junction Temperature

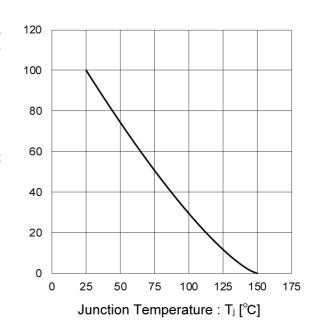
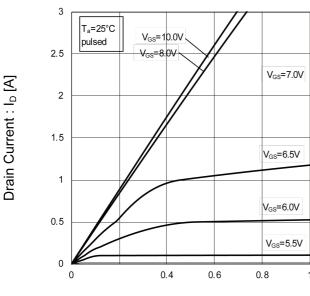
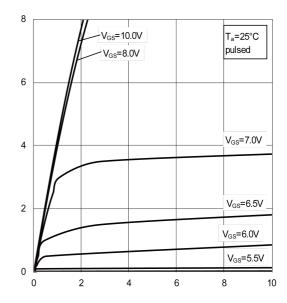


Fig.6 Typical Output Characteristics(I)



Drain - Source Voltage : $V_{DS}[V]$

Fig.7 Typical Output Characteristics(II)



Drain - Source Voltage: V_{DS}[V]

Drain Current: I_D [A]

Fig.8 Breakdown Voltage vs. Junction Temperature

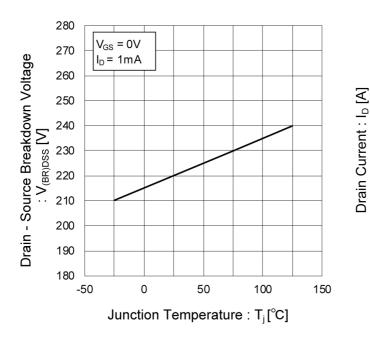
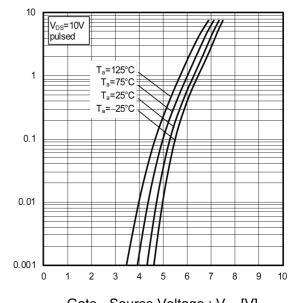


Fig.9 Typical Transfer Characteristics



Gate - Source Voltage : $V_{\text{GS}}[V]$

Fig.10 Gate Threshold Voltage vs. Junction Temperature

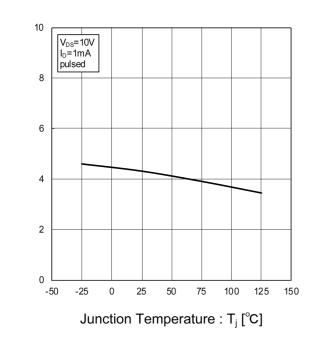
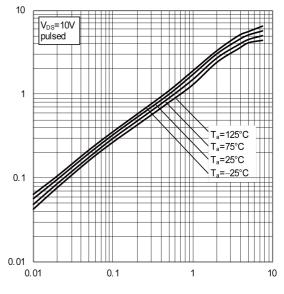


Fig.11 Transconductance vs. Drain Current



Drain Current: I_D [A]

Gate Threshold Voltage : $V_{GS(th)}$ [V]

Transconductance : g_{fs} [S]

Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage

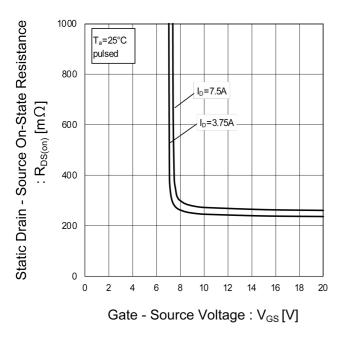
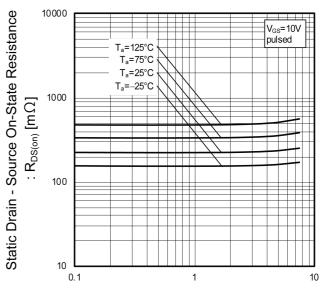


Fig.13 Static Drain - Source On - State Resistance vs. Drain Current(I)



Drain Current : I_D [A]

Fig.14 Static Drain - Source On - State Resistance vs. Junction Temperature

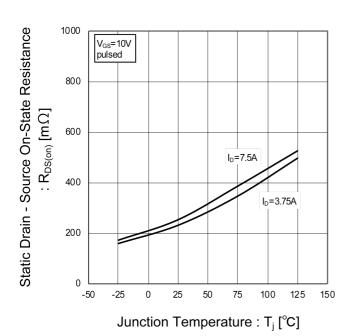


Fig.17 Typical Capacitance vs. Drain - Source Voltage

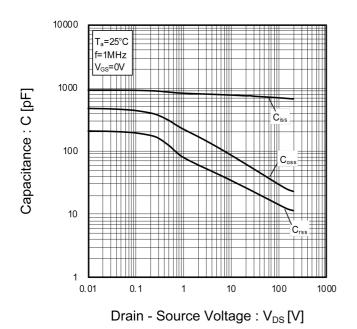


Fig.18 Switching Characteristics

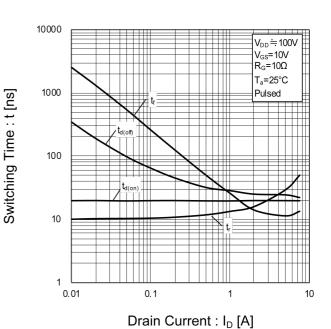
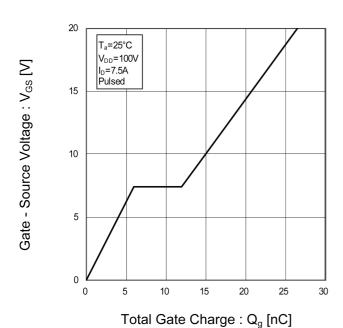


Fig.19 Dynamic Input Characteristics

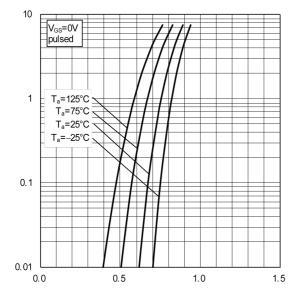


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Inverse Diode Forward Current : Is [A]

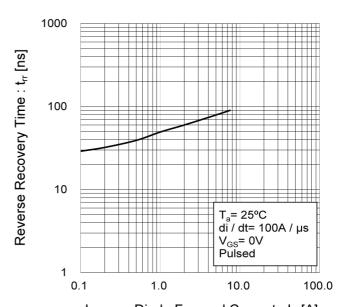
• Electrical characteristic curves

Fig.20 Source Current vs. Source-Drain Voltage



Source - Drain Voltage : V_{SD} [V]

Fig.21 Source Current vs. Reverse Recovery Time



Inverse Diode Forward Current : I_S [A]

Measurement circuits

Fig.1-1 Switching Time Measurement Circuit

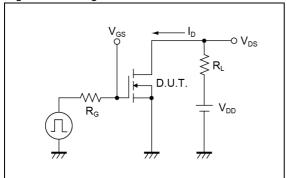


Fig.2-1 Gate Charge Measurement Circuit

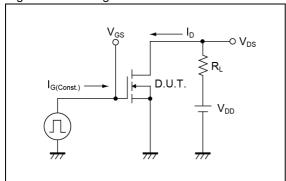


Fig.3-1 Avalanche Measurement Circuit

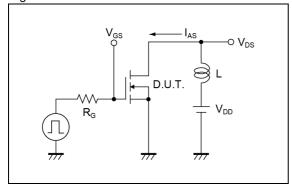


Fig.1-2 Switching Waveforms

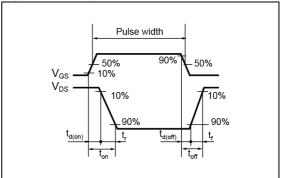


Fig.2-2 Gate Charge Waveform

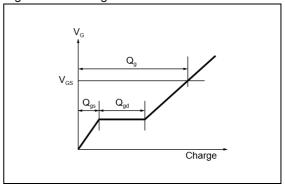
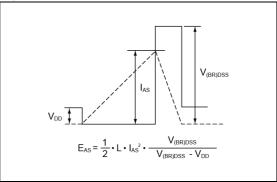
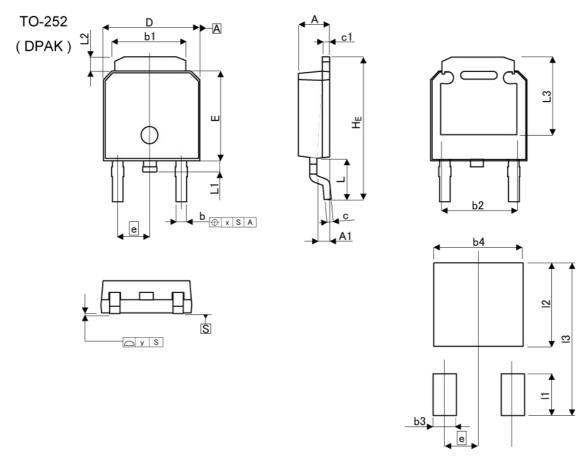


Fig.3-2 Avalanche Waveform



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

| DIM | MILIME | TERS | INC | HES | |
|-----|--------|-------|------------------|-------|--|
| DIM | MIN | MAX | MIN | MAX | |
| Α | 2.20 | 2.40 | 0.087 | 0.094 | |
| A1 | 0.70 | 1.10 | 0.028 | 0.043 | |
| b | 0.60 | 0.90 | 0.024 | 0.035 | |
| b1 | 5.20 | 5.50 | 0.205 | 0.217 | |
| b2 | 4. | 80 | 0.1 | 89 | |
| С | 0.40 | 0.60 | 0.016 | 0.024 | |
| c1 | 0.40 | 0.60 | 0.016 | 0.024 | |
| D | 6.40 | 6.80 | 0.252 | 0.268 | |
| е | 2. | 30 | 0.0 | 91 | |
| E | 6.00 | 6.40 | 0.236 | 0.252 | |
| HE | 9.40 | 10.40 | 0.370 | 0.409 | |
| L | 2. | 90 | 0.1 | 14 | |
| L1 | 0.60 | 1.00 | 0.024 | 0.039 | |
| L2 | 0.70 | 1.30 | 0.028 | 0.051 | |
| L3 | 5. | 30 | 0.2 | 209 | |
| Х | - | 0.25 | - | 0.010 | |
| у | - | 0.10 | , - , | 0.004 | |
| DIM | MILIME | TERS | INC | HES | |
| DIM | MIN | MAX | MIN | MAX | |
| b3 | - 1 | 1.15 | - | 0.045 | |
| b4 | - | 5.55 | 1 . | 0.219 | |
| l1 | - | 2.77 | - | 0.109 | |
| 12 | - | 5.50 | - | 0.217 | |
| 13 | - | 10.40 | - | 0.409 | |

Dimension in mm/inches



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 - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
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- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
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 - [c] the Products are exposed to direct sunshine or condensation
 - [d] the Products are exposed to high Electrostatic
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